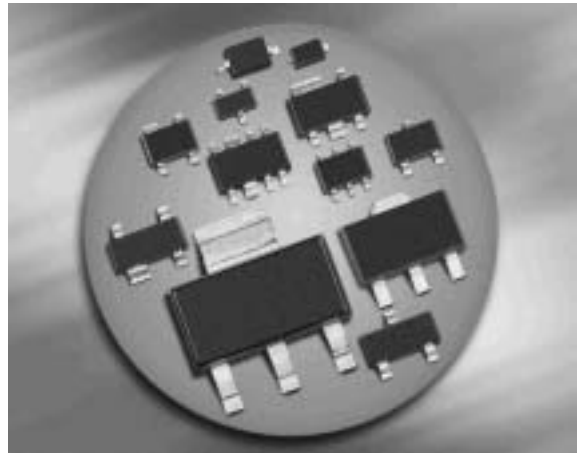
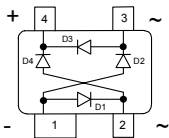


Low VF Schottky Diode Array

- Reverse voltage: 30 V
- Forward current: 0.9 A
- Small diode quad array for polarity independence, reverse polarity protection and low loss bridge rectification
- Very low forward voltage:
0.5 V typ. @ 0.7 A (per diode)
- Fast switching
- Pb-free (ROHS compliant) package¹⁾
- Qualified according AEC Q101



BAS3007A-RPP



Type	Package	Configuration	Marking
BAS3007A-RPP	SOT143	bridge	E1s

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage ²⁾	V_R	30	V
Peak reverse voltage ²⁾	V_{RM}	30	
RMS reverse voltage ²⁾	$V_{R(RMS)}$	21	
Forward current ²⁾	I_F		mA
$T_S \leq 46^\circ\text{C}$		900	
$T_S \leq 82^\circ\text{C}$		700	
Non-repetitive peak surge forward current ($t \leq 10$ ms)	I_{FSM}	5	A
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

¹⁾Pb-containing package may be available upon special request

²⁾For $T_A > 25^\circ\text{C}$ the derating of V_R and I_F has to be considered. Please refer to the attached curves.

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}	≤ 95	K/W

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC Characteristics

Reverse current (per diode) ²⁾	I_R				μA
$V_R = 12\text{ V}$		-	-	30	
$V_R = 30\text{ V}$		-	-	350	
Forward voltage (per diode) ²⁾³⁾	V_F				V
$I_F = 100\text{ mA}$		-	0.35	0.4	
$I_F = 350\text{ mA}$		-	0.4	0.5	
$I_F = 500\text{ mA}$		-	0.45	0.55	
$I_F = 700\text{ mA}$		-	0.5	0.6	
$I_F = 900\text{ mA}$		-	0.6	0.7	

AC Characteristics

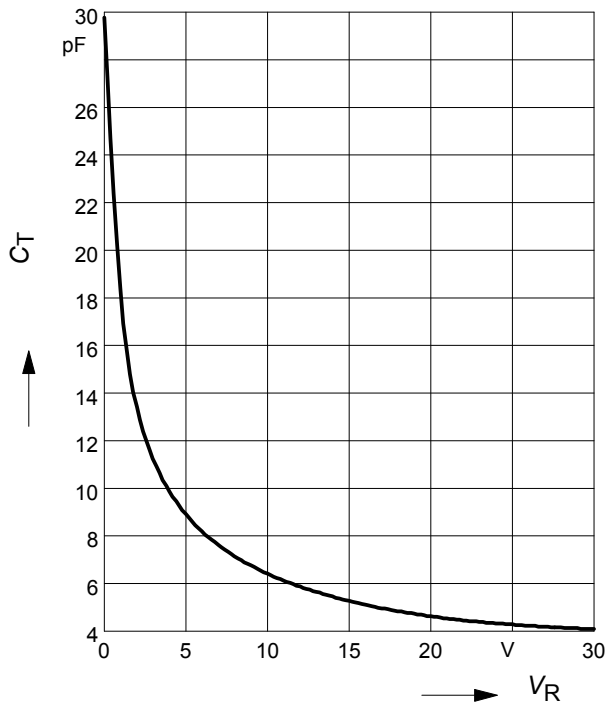
Diode capacitance (per diode)	C_T	-	9	15	pF
$V_R = 5\text{ V}$, $f = 1\text{ MHz}$					

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

²⁾Pulsed test, $t_p = 300\text{ }\mu\text{s}$; $D = 0.01$
³⁾When used as shown for Reverse Polarity Protection (RPP, see page 4), the voltage available to the circuit being protected will be two diode drops below the power supply voltage. In other words, the supply current will pass through two diodes.

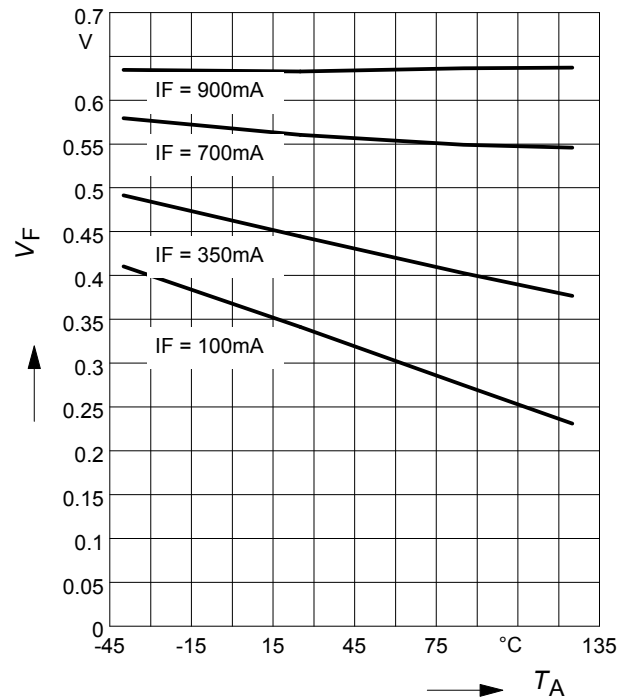
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$ (per diode)



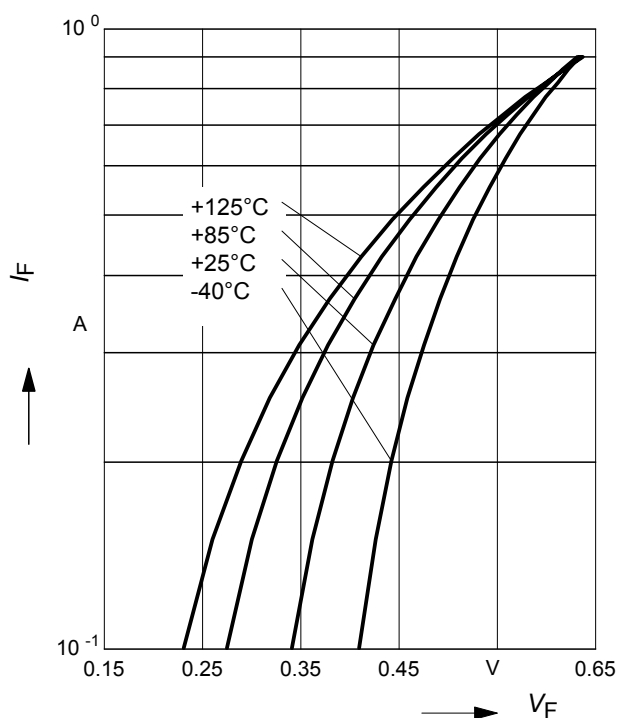
Forward Voltage $V_F = f(T_A)$

$I_F = \text{Parameter}$ (per diode)



Forward current $I_F = f(V_F)$

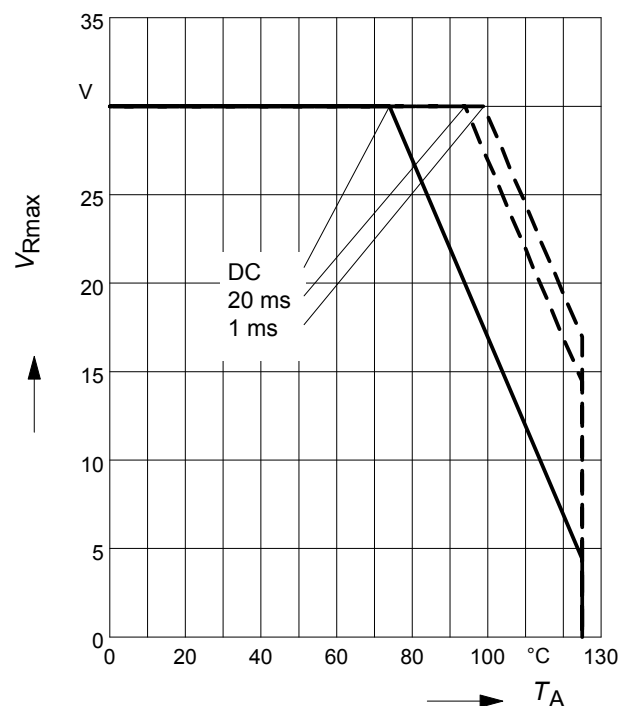
$T_A = \text{Parameter}$ (per diode)



Permissible Reverse voltage $V_R = f(T_A)$

$t_p = \text{Parameter}$, Duty cycle < 0.01

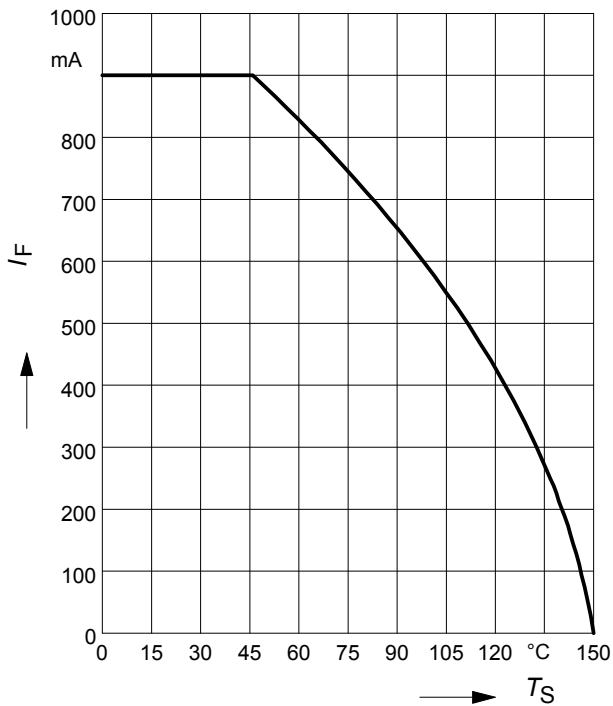
Device mounted on PCB with $R_{th} = 160\text{ K/W}$



Forward current $I_F = f(T_S)$

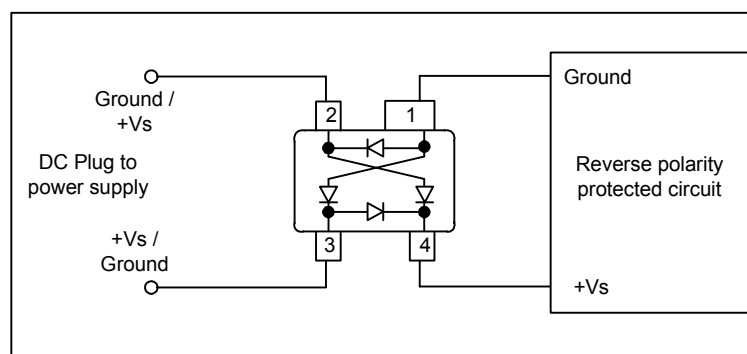
Current flows through two chips

per package at the same time (per array)



Application example BAS3007A-RPP

Advanced Reverse Polarity Protection(RPP): due to diode orientation, circuit at the right will be protected from damage and will also function normally in the event reverse polarity is applied to pins 2 and 3 of the BAS3007A-RPP.



Technical drawing of a 4-pin connector. The drawing includes a perspective view of the component and two orthographic views (top and side) with detailed dimensions and tolerances.

Top View Dimensions:

- Overall width: 2.9 ± 0.1
- Pin pitch (center-to-center): 1.9
- Pin width: 0.2
- Pin spacing (from edge to center): $0.8^{+0.1}_{-0.05}$
- Pin diameter: $0.4^{+0.1}_{-0.05}$
- Pin length: 1.7
- Pin diameter tolerance: $\oplus 0.25 \text{ M B}$

Side View Dimensions:

- Overall height: 2.4 ± 0.15
- Pin height: 1 ± 0.1
- Pin diameter: 0.1 MAX.
- Pin angle: 10° MAX.
- Pin diameter: $0.08 \dots 0.15$
- Pin angle: $0 \dots 8^\circ$
- Pin diameter: 1.3 ± 0.1
- Pin diameter tolerance: $\oplus 0.2 \text{ M A}$

Diagram illustrating the marking on the BFP181 package:

- Manufacturer:** infineon
- Date code (YM):** 2005, June
- Pin 1:** Indicated by a line pointing to the first pin.
- Type code:** BFP181

Technical drawing of a mechanical part showing top and side views with dimensions:

- Top View Dimensions:**
 - Overall width: 4
 - Overall height: 8
 - Distance from left edge to first hole center: 3.15
 - Distance between hole centers: 2.6
 - Distance from last hole center to right edge: 0.2
- Side View Dimensions:**
 - Overall height: 1.15
 - Distance from bottom edge to hole center: 0.2
- Other Features:**
 - Three circular holes are shown in the top view.
 - A rectangular feature is labeled "Pin 1" with an arrow pointing to it.
 - Section lines are present in the side view, indicating a cross-section.

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